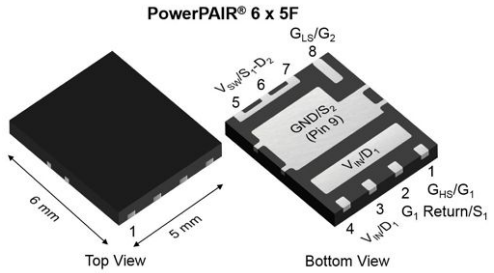
Dual N-Channel 30 V (D-S) MOSFET



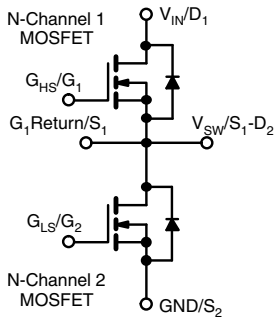
FEATURES

- TrenchFET® Gen V power MOSFET
- 100 % R_g and UIS tested
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

RoHS COMPLIANT
HALOGEN FREE

APPLICATIONS

- CPU core power
- Computer / server peripherals
- POL
- Synchronous buck converter
- Telecom DC/DC



PRODUCT SUMMARY

	CHANNEL-1	CHANNEL-2
V_{DS} (V)	30	30
$R_{DS(on)}$ max. (Ω) at V_{GS} = 10 V	0.00245	0.00075
$R_{DS(on)}$ max. (Ω) at V_{GS} = 4.5 V	0.00380	0.00120
Q_g typ. (nC)	8.5	35
I_D (A) [a]	88	248
Configuration	Dual	

ORDERING INFORMATION

Package	PowerPAIR 6 x 5F
Lead (Pb)-free and halogen-free	SiZF928DT-T1-GE3

ABSOLUTE MAXIMUM RATINGS (T_A = 25 °C, unless otherwise noted)

PARAMETER		SYMBOL	CHANNEL-1	CHANNEL-2	UNIT
Drain-source voltage		V_{DS}	30	30	V
Gate-source voltage		V_{GS}	+16, -12	+16, -12	
Continuous drain current (T_J = 150 °C)	T_C = 25 °C	I_D	88	248	A
	T_C = 70 °C		70	198	
	T_A = 25 °C		33 [b, c]	61 [b, c]	
	T_A = 70 °C		26 [b, c]	49 [b, c]	
Pulsed drain current (t = 100 µs)		I_{DM}	150	400	
Continuous source-drain diode current	T_C = 25 °C	I_S	26	67	
	T_A = 25 °C		3.6 [b, c]	7.4 [b, c]	
Single pulse avalanche current	L = 0.1 mH	I_{AS}	20	50	
Single pulse avalanche energy		E_{AS}	20	125	mJ
Maximum power dissipation	T_C = 25 °C	P_D	28	74	W
	T_C = 70 °C		18	47	
	T_A = 25 °C		3.9 [b, c]	4.5 [b, c]	
	T_A = 70 °C		2.5 [b, c]	2.9 [b, c]	
Operating junction and storage temperature range		T_J, T_{stg}	-55 to +150		°C
Soldering recommendations (peak temperature) [d, e]			260		

THERMAL RESISTANCE RATINGS

PARAMETER		SYMBOL	CHANNEL-1		CHANNEL-2		UNIT
			TYP.	MAX.	TYP.	MAX.	
Maximum junction-to-ambient [b, f]	t ≤ 10 s	R_{thJA}	25	32	22	28	°C/W
Maximum junction-to-case (source)	Steady state	R_{thJC}	3.5	4.4	1.3	1.7	

Notes

a. T_C = 25 °C
b. Surface mounted on 1" x 1" FR4 board
c. t = 10 s
d. See solder profile (www.vishay.com/doc?73257). The PowerPAIR is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection
e. Rework conditions: manual soldering with a soldering iron is not recommended for leadless components
f. Maximum under steady state conditions is 65 °C/W for channel-1 and 65 °C/W for channel-2

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SPECIFICATIONS (T_J = 25 °C, unless otherwise noted)							
PARAMETER	**SYMBOL**	**TEST CONDITIONS**		**MIN.**	**TYP.**	**MAX.**	**UNIT**
Static							
Drain-source breakdown voltage	V_{DS}	V_{GS} = 0 V, I_D = 1 mA	Ch-1	30	-	-	V
			Ch-2	30	-	-	
Gate-source threshold voltage	$V_{GS(th)}$	V_{DS} = V_{GS}, I_D = 250 µA	Ch-1	1	-	2	
			Ch-2	1	-	2	
Gate-source leakage	I_{GSS}	V_{DS} = 0 V, V_{GS} = +16 V, -12 V	Ch-1	-	-	± 100	nA
		V_{DS} = 0 V, V_{GS} = +16 V, -12 V	Ch-2	-	-	± 100	
Zero Gate voltage drain current	I_{DSS}	V_{DS} = 24 V, V_{GS} = 0 V	Ch-1	-	-	1	µA
			Ch-2	-	-	1	
		V_{DS} = 24 V, V_{GS} = 0 V, T_J = 55 °C	Ch-1	-	-	5	
			Ch-2	-	-	5	
On-state drain current [b]	$I_{D(on)}$	V_{DS} ≥ 5 V, V_{GS} = 10 V	Ch-1	20	-	-	A
			Ch-2	20	-	-	
Drain-source on-state resistance [b]	$R_{DS(on)}$	V_{GS} = 10 V, I_D = 10 A	Ch-1	-	0.00180	0.00245	Ω
		V_{GS} = 10 V, I_D = 15 A	Ch-2	-	0.00053	0.00075	
		V_{GS} = 4.5 V, I_D = 5 A	Ch-1	-	0.00270	0.00380	
		V_{GS} = 4.5 V, I_D = 10 A	Ch-2	-	0.00082	0.00120	
Forward transconductance [b]	g_{fs}	V_{DS} = 15 V, I_D = 40 A	Ch-1	-	97	-	S
		V_{DS} = 15 V, I_D = 50 A	Ch-2		175	-	
Dynamic [a]							
Input capacitance	C_{iss}	Channel-1 V_{DS} = 15 V, V_{GS} = 0 V, f = 1 MHz Channel-2 V_{DS} = 15 V, V_{GS} = 0 V, f = 1 MHz	Ch-1	-	1265	-	pF
			Ch-2	-	5650	-	
Output capacitance	C_{oss}		Ch-1	-	455	-	
			Ch-2	-	1796	-	
Reverse transfer capacitance	C_{rss}		Ch-1	-	30	-	
			Ch-2	-	125	-	
C_{rss}/C_{iss} ratio			Ch-1	-	0.023	0.046	
			Ch-2		0.023	0.046	
Total gate charge	Q_g	V_{DS} = 15 V, V_{GS} = 10 V, I_D = 10 A	Ch-1	-	18.5	28	nC
		V_{DS} = 15 V, V_{GS} = 10 V, I_D = 10 A	Ch-2	-	77	116	
		V_{DS} = 15 V, V_{GS} = 4.5 V, I_D = 10 A	Ch-1		8.5	12.8	
		V_{DS} = 15 V, V_{GS} = 4.5 V, I_D = 10 A	Ch-2	-	35	53	
Gate-source charge	Q_{gs}	Channel-1 V_{DS} = 15 V, V_{GS} = 4.5 V, I_D = 10 A	Ch-1	-	3.9	-	
			Ch-2	-	17	-	
Gate-drain charge	Q_{gd}	Channel-2 V_{DS} = 15 V, V_{GS} = 4.5 V, I_D = 10 A	Ch-1	-	1.6	-	
			Ch-2	-	5.2	-	
Output charge	Q_{oss}	V_{DS} = 15 V, V_{GS} = 0 V	Ch-1	-	13	-	
			Ch-2	-	51	-	
Gate resistance	R_g	f = 1 MHz	Ch-1	0.2	1	2	Ω
			Ch-2	0.15	0.75	1.5	

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SPECIFICATIONS (T_J = 25 °C, unless otherwise noted)							
PARAMETER	**SYMBOL**	**TEST CONDITIONS**		**MIN.**	**TYP.**	**MAX.**	**UNIT**
Dynamic [a]							
Turn-on delay time	$t_{d(on)}$	Channel-1 V_{DD} = 15 V, R_L = 1.5 Ω $I_D \cong$ 10 A, V_{GEN} = 4.5 V, R_g = 1 Ω	Ch-1	-	20	40	ns
			Ch-2	-	38	80	
Rise time	t_r		Ch-1	-	92	185	
			Ch-2	-	95	190	
Turn-off delay time	$t_{d(off)}$	Channel-2 V_{DD} = 15 V, R_L = 3 Ω $I_D \cong$ 10 A, V_{GEN} = 4.5 V, R_g = 1 Ω	Ch-1	-	22	45	
			Ch-2	-	46	90	
Fall time	t_f		Ch-1	-	6	15	
			Ch-2	-	17	35	
Turn-on delay time	$t_{d(on)}$	Channel-1 V_{DD} = 15 V, R_L = 3 Ω $I_D \cong$ 10 A, V_{GEN} = 10 V, R_g = 1 Ω	Ch-1	-	11	20	
			Ch-2	-	18	40	
Rise time	t_r		Ch-1	-	5	10	
			Ch-2	-	48	100	
Turn-off delay time	$t_{d(off)}$	Channel-2 V_{DD} = 15 V, R_L = 3 Ω $I_D \cong$ 10 A, V_{GEN} = 10 V, R_g = 1 Ω	Ch-1	-	22	45	
			Ch-2	-	45	90	
Fall time	t_f		Ch-1	-	5	10	
			Ch-2	-	10	20	
Drain-Source Body Diode Characteristics							
Continuous source-drain diode current	I_S	T_C = 25 °C	Ch-1	-	-	26	A
			Ch-2	-	-	67	
Pulse diode forward current [a]	I_{SM}		Ch-1	-	-	150	
			Ch-2	-	-	400	
Body diode voltage	V_{SD}	I_S = 10 A, V_{GS} = 0 V	Ch-1	-	0.78	1.1	V
		I_S = 3 A, V_{GS} = 0 V	Ch-2	-	0.75	1.1	
Body diode reverse recovery time	t_{rr}	Channel-1 I_F = 10 A, di/dt = 100 A/µs, T_J = 25 °C	Ch-1	-	20	40	ns
			Ch-2	-	50	100	
Body diode reverse recovery charge	Q_{rr}		Ch-1	-	10	20	nC
			Ch-2	-	50	100	
Reverse recovery fall time	t_a	Channel-2 I_F = 10 A, di/dt = 100 A/µs, T_J = 25 °C	Ch-1	-	11.5	-	ns
			Ch-2	-	26	-	
Reverse recovery rise time	t_b		Ch-1	-	8.5	-	
			Ch-2	-	24	-	

Notes

a. Guaranteed by design, not subject to production testing

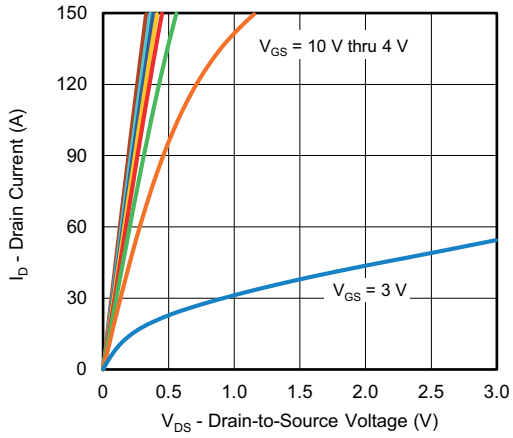
b. Pulse test; pulse width ≤ 300 µs, duty cycle ≤ 2 %

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

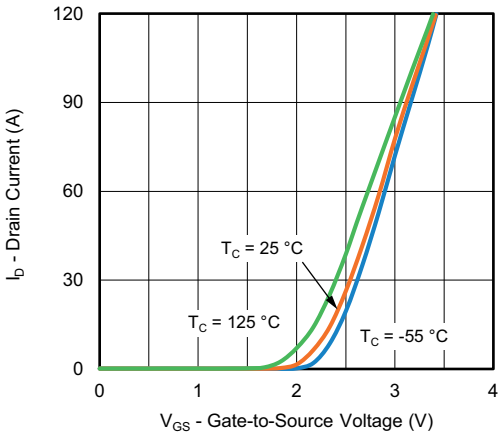
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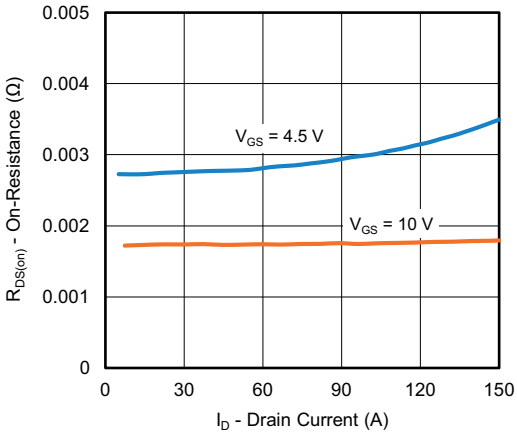
CHANNEL-1 TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



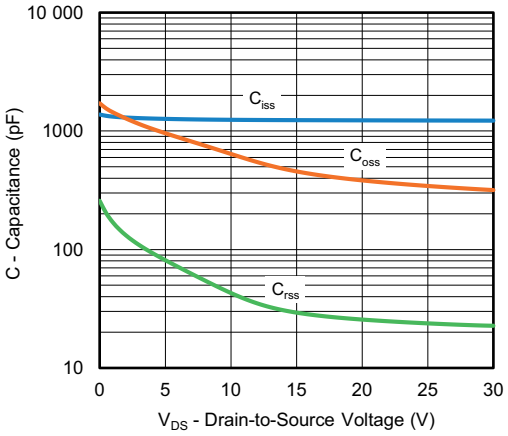
Output Characteristics



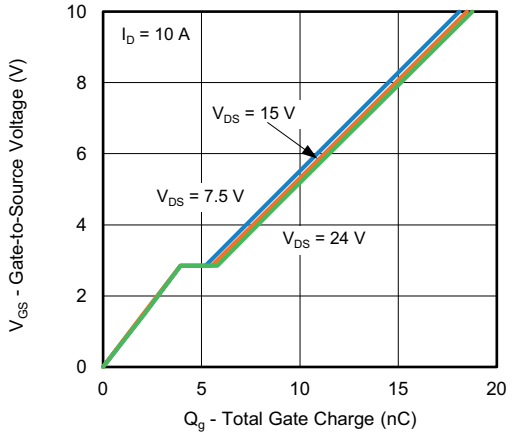
Transfer Characteristics



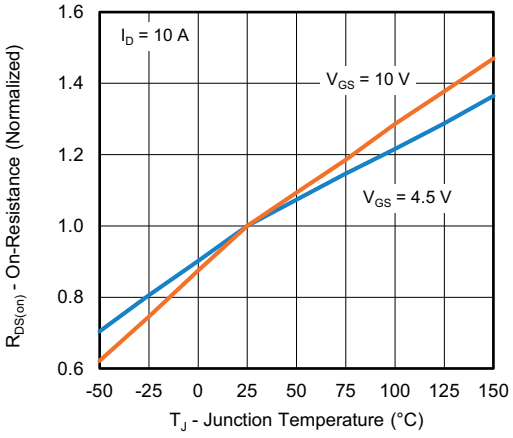
On-Resistance vs. Drain Current



Capacitance



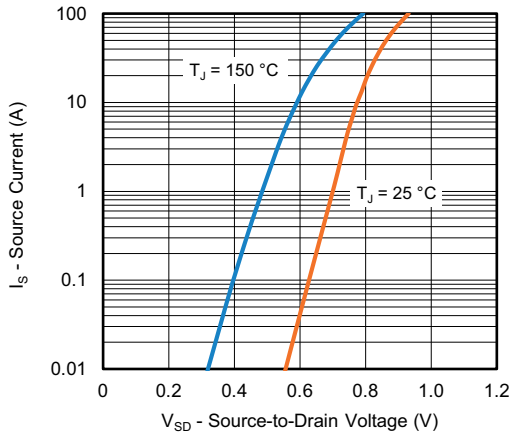
Gate Charge



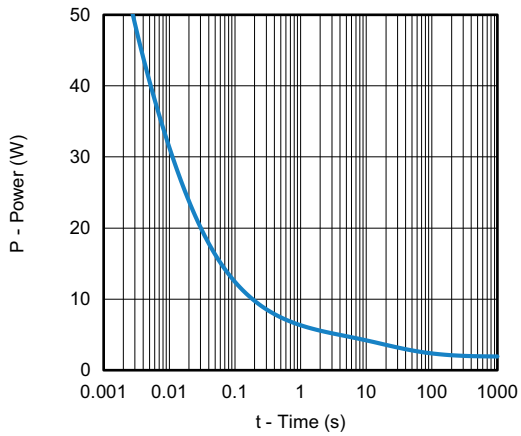
On-Resistance vs. Junction Temperature

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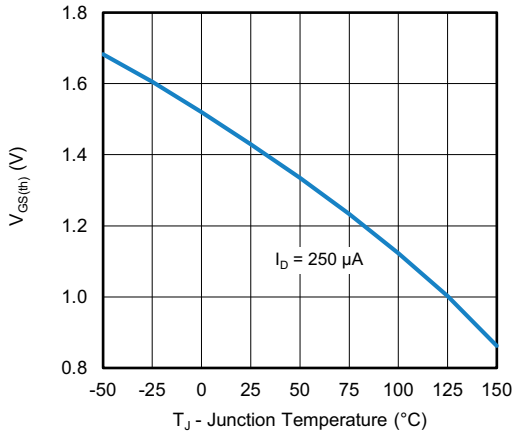
CHANNEL-1 TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



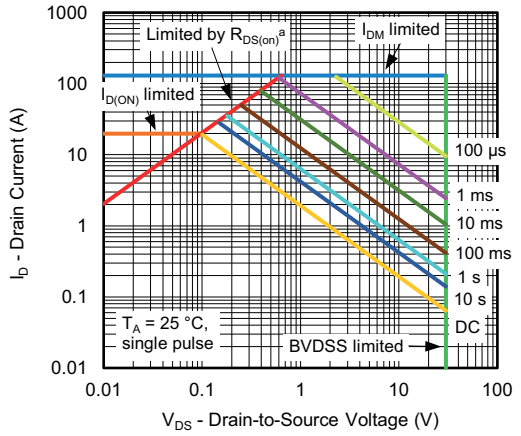
Source-Drain Diode Forward Voltage



Single Pulse Power, Junction-to-Ambient



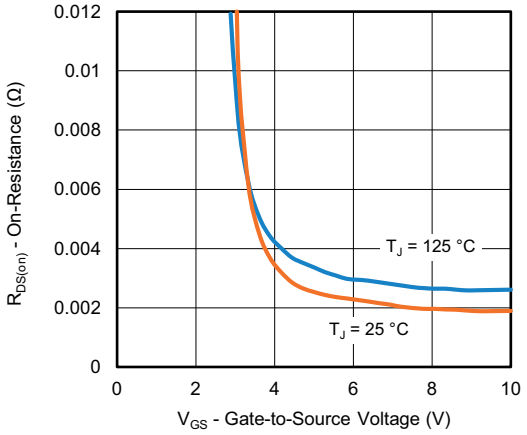
Threshold Voltage



Safe Operating Area, Junction-to-Ambient

Note

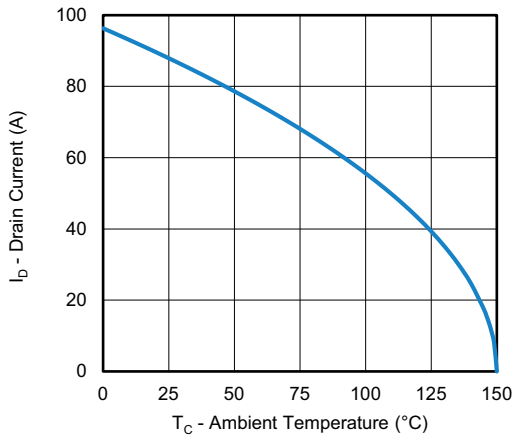
a. V_{GS} > minimum V_{GS} at which $R_{DS(on)}$ is specified



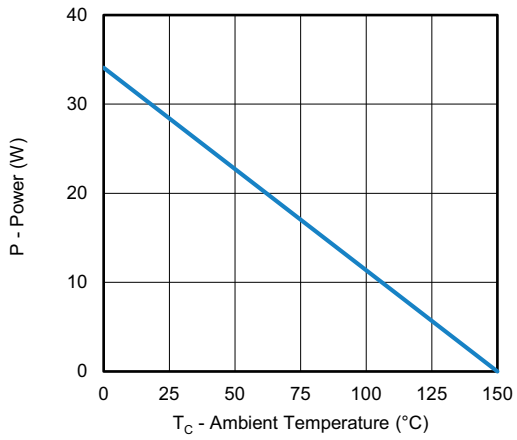
On-Resistance vs. Gate-to-Source Voltage

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CHANNEL-1 TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



Current Derating [a]



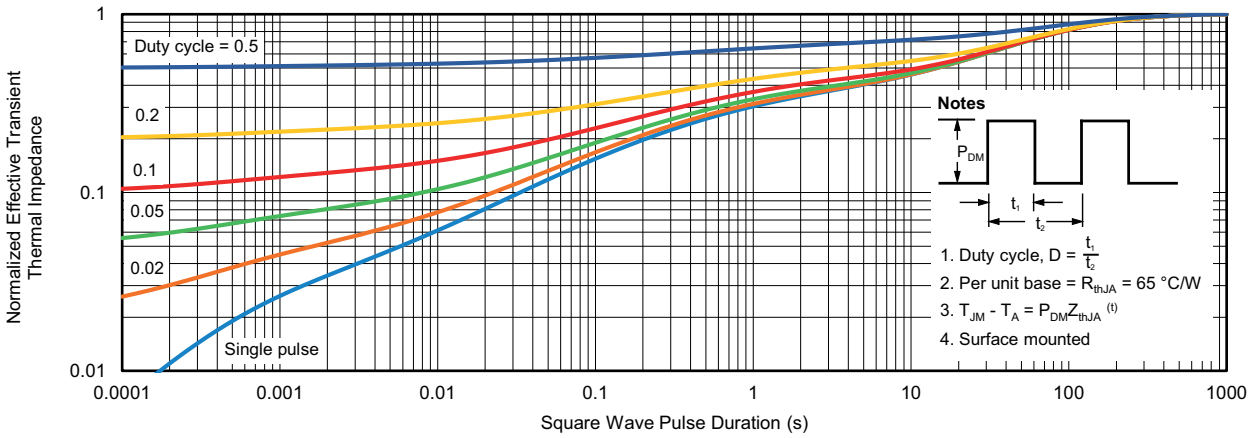
Power, Junction-to-Case

Note

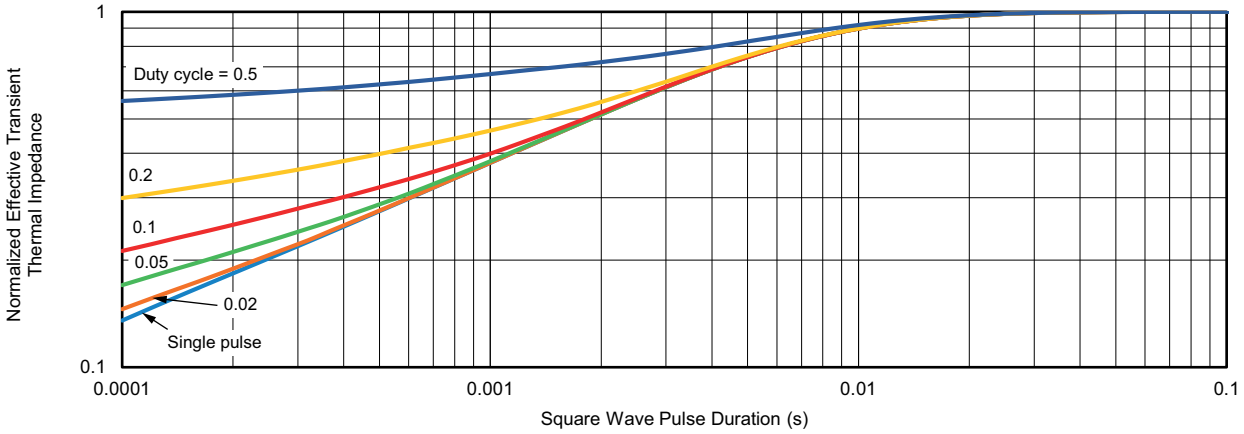
a. The power dissipation P_D is based on T_J max. = 150 °C, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit

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CHANNEL-1 TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



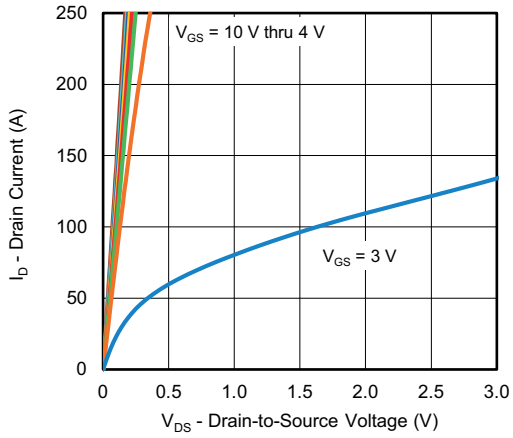
Normalized Thermal Transient Impedance, Junction-to-Ambient



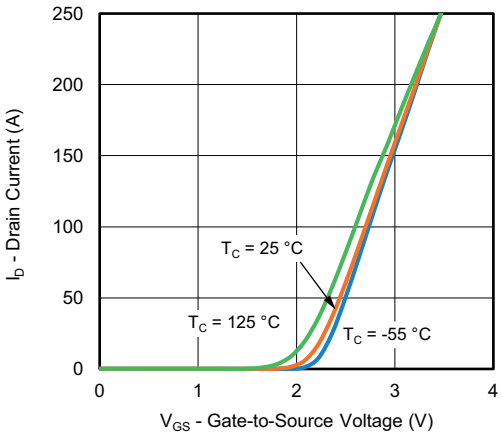
Normalized Thermal Transient Impedance, Junction-to-Case

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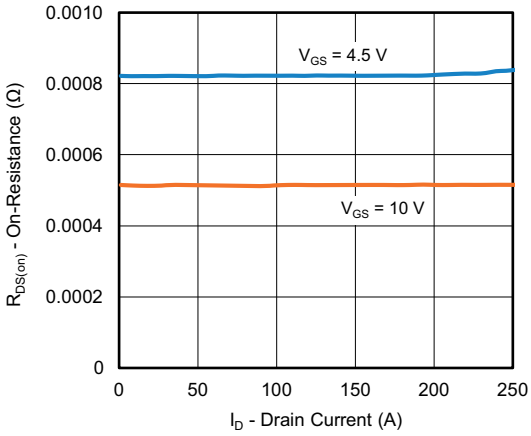
CHANNEL-2 TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



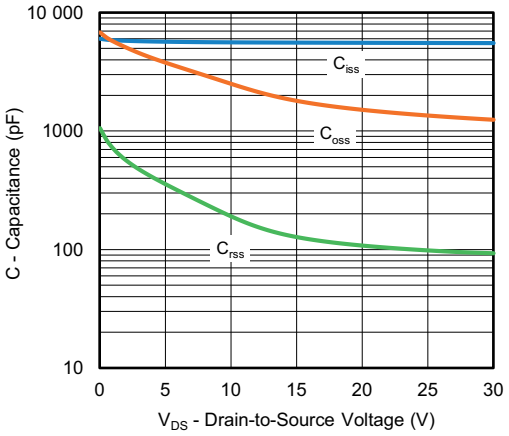
Output Characteristics



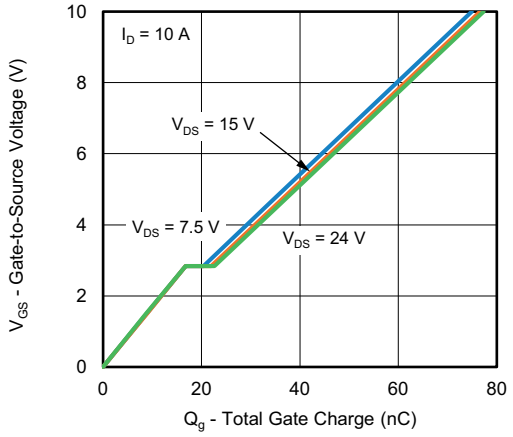
Transfer Characteristics



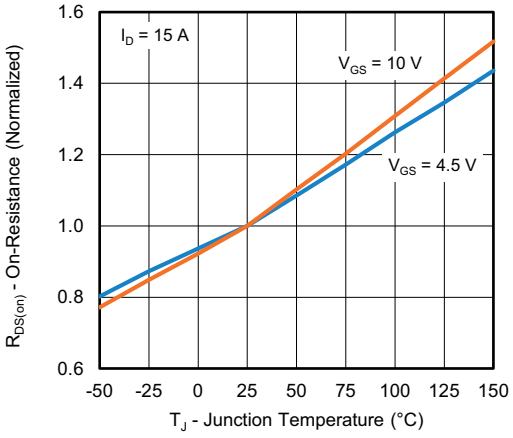
On-Resistance vs. Drain Current



Capacitance



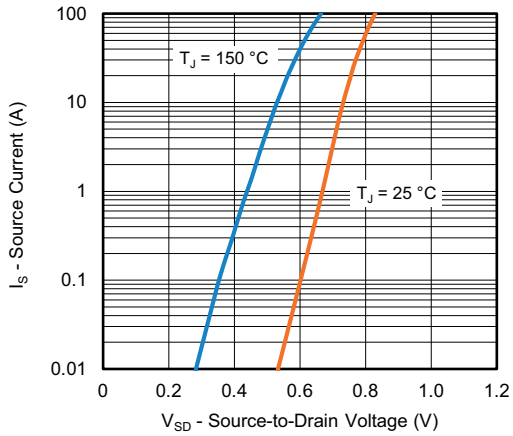
Gate Charge



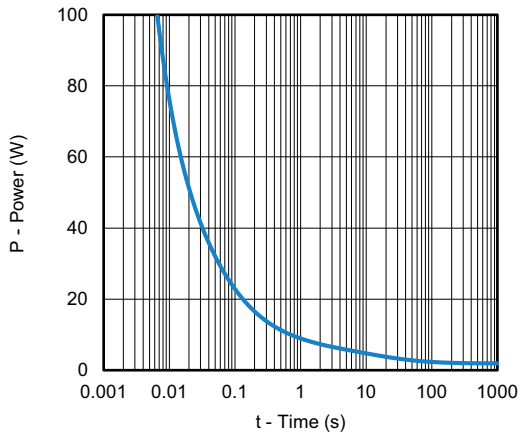
On-Resistance vs. Junction Temperature

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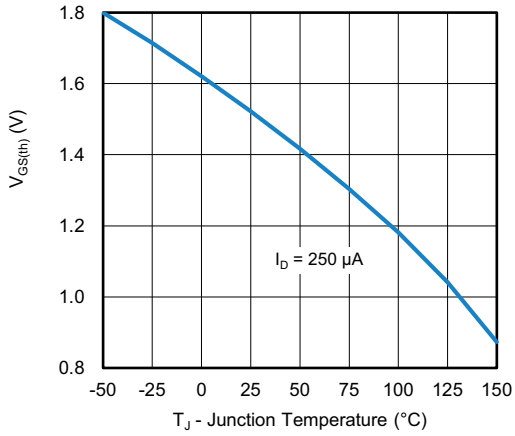
CHANNEL-2 TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



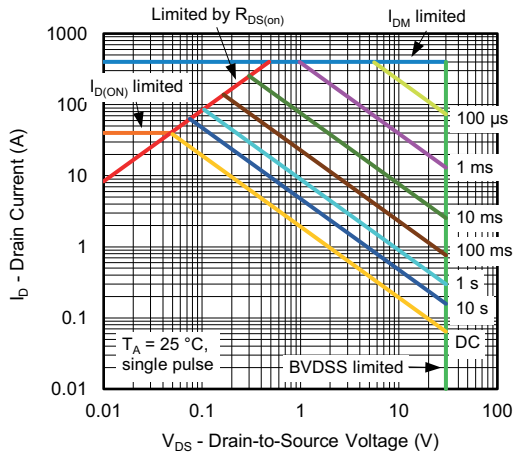
Source-Drain Diode Forward Voltage



Single Pulse Power, Junction-to-Ambient



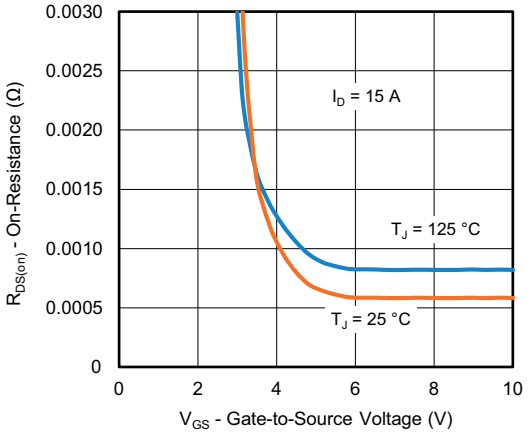
Threshold Voltage



Safe Operating Area, Junction-to-Ambient

Note

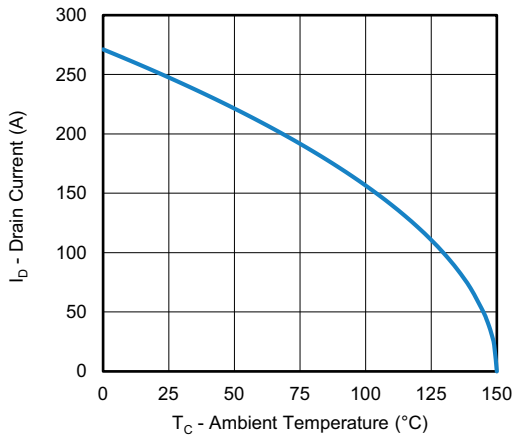
a. V_{GS} > minimum V_{GS} at which $R_{DS(on)}$ is specified



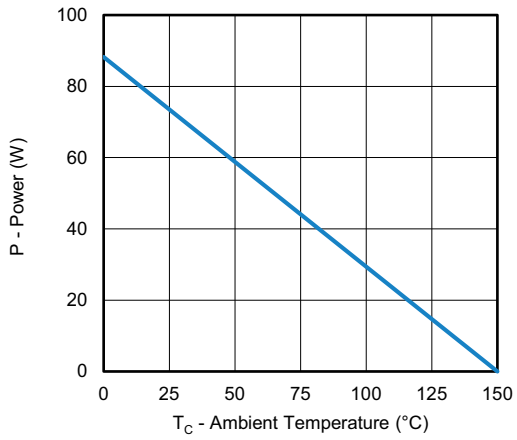
On-Resistance vs. Gate-to-Source Voltage

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CHANNEL-2 TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



Current Derating [a]



Power, Junction-to-Case

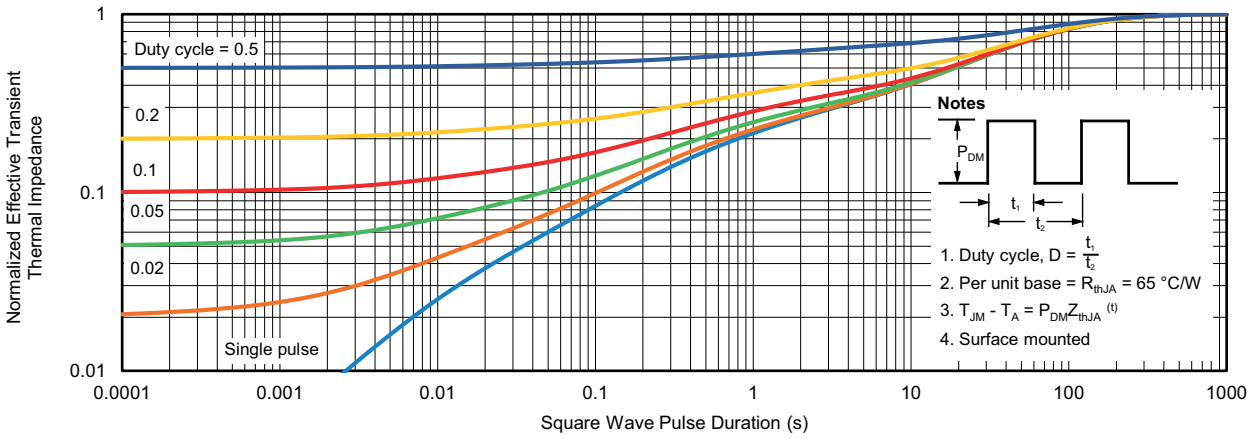
Note

a. The power dissipation P_D is based on T_J max. = 150 °C, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit

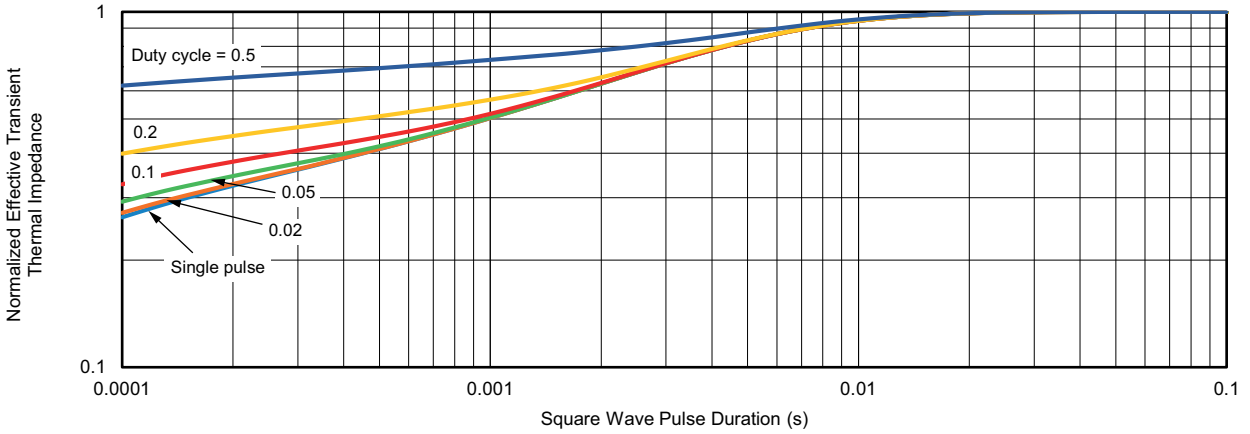
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CHANNEL-2 TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient



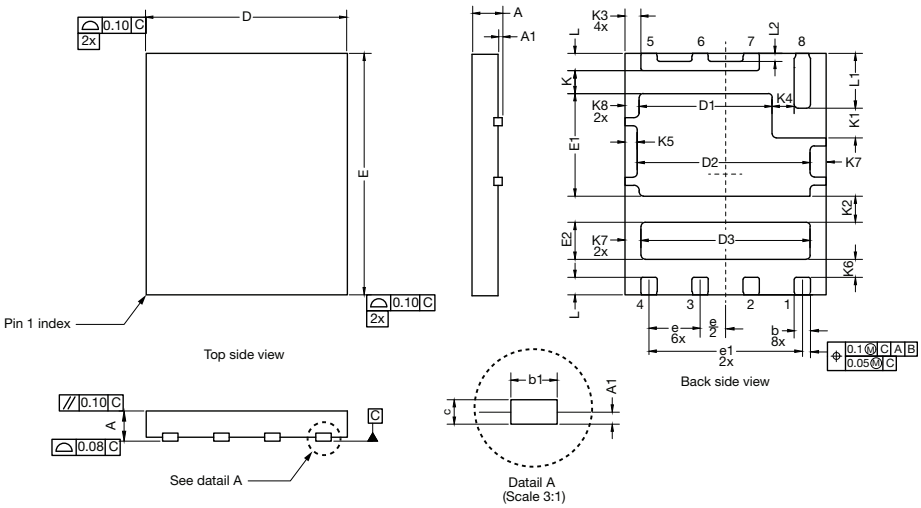
Normalized Thermal Transient Impedance, Junction-to-Case

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PowerPAIR® 6 x 5 F Case Outline



DIMENSION	MILLIMETERS			INCHES		
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.
A	0.70	0.75	0.80	0.028	0.030	0.031
A1	0.00	-	0.10	0.000	-	0.004
b	0.35	0.41	0.46	0.014	0.016	0.018
b1		0.38 ref.			0.015 ref.	
c	0.15	0.20	0.25	0.006	0.008	0.010
D	4.90	5.00	5.10	0.193	0.197	0.201
D1	3.26	3.31	3.36	0.128	0.130	0.132
D2	4.20	4.30	4.40	0.165	0.169	0.173
D3	4.15	4.20	4.25	0.163	0.165	0.167
E	5.90	6.00	6.10	0.232	0.236	0.240
E1	2.50	2.55	2.60	0.098	0.100	0.102
E2	0.87	0.92	0.97	0.034	0.036	0.038
e		1.27 BSC			0.050 BSC	
e1		3.81 BSC			0.150 BSC	
K	0.52	0.57	0.62	0.020	0.022	0.024
K1	0.69	0.74	0.79	0.027	0.029	0.031
K2	0.60	0.65	0.70	0.024	0.026	0.028
K3		0.39 BSC			0.015 BSC	
K4	0.50	0.55	0.60	0.020	0.022	0.024
K5	0.25	0.30	0.35	0.010	0.012	0.014
K6	0.40	0.45	0.50	0.016	0.018	0.020
K7	0.35	0.40	0.45	0.014	0.016	0.018
K8	0.30	0.35	0.40	0.012	0.014	0.016
L	0.33	0.43	0.53	0.013	0.017	0.021
L1	1.31	1.36	1.41	0.052	0.054	0.056
L2		0.20 ref.			0.008 ref.	
ECN: T20-0097-Rev. C, 25-Feb-2020 DWG: 6043						

Note

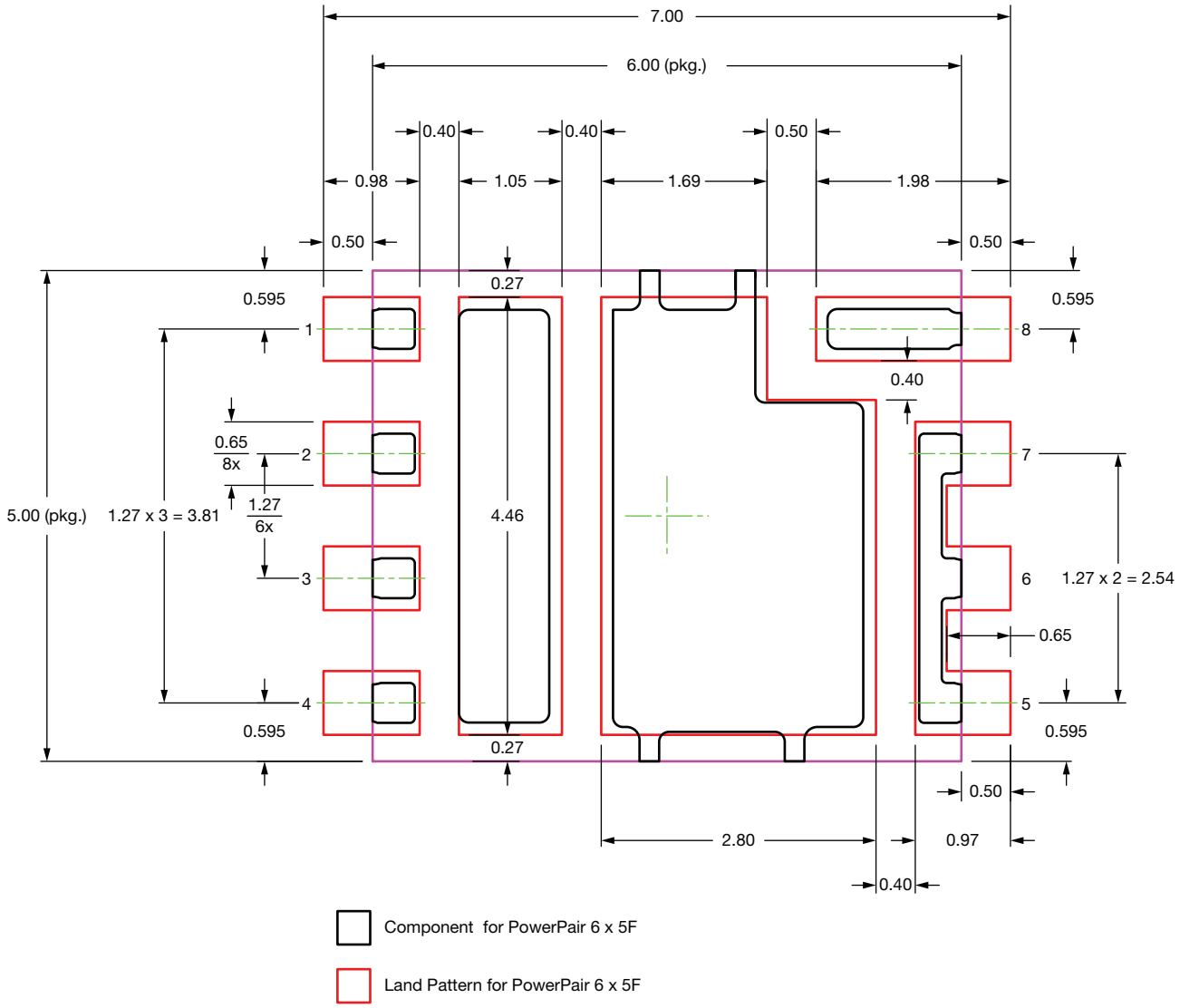
- Millimeters will govern

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Recommended Minimum PADs for PowerPAIR® 6 x 5F



Note

- Dimensions in millimeters

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